









#### SN54HC02, SN74HC02

SCLS076F - DECEMBER 1982-REVISED APRIL 2015

# SNx4HC02 Quadruple 2-Input Positive-NOR Gates

#### **Features**

- Wide Operating Voltage Range of 2 V to 6 V
- Outputs Can Drive Up to 10 LSTTL Loads
- Low Power Consumption: Maximum I<sub>CC</sub> of 20 µA
- Typical  $t_{pd} = 8 \text{ ns}$
- ±4-mA Output Drive at 5 V
- Low Input Current of 1-µA Maximum

## **Applications**

- Education
- Toys
- Musical Instruments
- Medical Healthcare and Fitness
- Grid Infrastructure
- Electronic Point of Sale
- Test and Measurement
- Factory Automation and Control
- **Building Automation**
- RS Latch
- Falling Edge Detector

## 3 Description

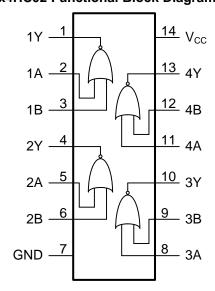
The SNx4HC02 devices contain four independent 2input NOR gates. They perform the Boolean function  $Y = \overline{A + B}$  or  $Y = \overline{A} \cdot \overline{B}$  in positive logic.

#### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74HC02D	SOIC (14)	4.90 mm × 3.91 mm
SN74HC02N	PDIP (14)	19.30 mm × 6.35 mm
SN74HC02PW	TSSOP (14)	5.00 mm × 4.40 mm
SN74HC02NS	SO (14)	10.30 mm × 5.30 mm
SN74HC02DB	SSOP (14)	6.20 mm × 5.30 mm
SN54HC02J	CDIP (14)	19.94 mm × 7.62 mm
SN54HC02W	CFP (14)	9.21 mm × 7.11 mm
SN54HC02FK	LCCC (20)	8.89 mm × 8.89 mm

<sup>(1)</sup> For all available packages, see the orderable addendum at the end of the data sheet.

# **SNx4HC02 Functional Block Diagram**



Copyright © 2016, Texas Instruments Incorporated



#### **Table of Contents**

1	Features 1	8.2	2 Functional Block Diagram	
2	Applications 1	8.3	3 Feature Description	8
3	Description 1	8.4	4 Device Functional Modes	8
4	Revision History	9 Ap	pplication and Implementation	10
5	Pin Configuration and Functions	9.	· +	
6	Specifications4		2 Typical Application	
-	6.1 Absolute Maximum Ratings 4	10 Pc	ower Supply Recommendations	11
	6.2 ESD Ratings – SN74HC02	11 La	yout	11
	6.3 Recommended Operating Conditions	11	.1 Layout Guidelines	1
	6.4 Thermal Information – SN74HC02	11	.2 Layout Example	1
	6.5 Thermal Information – SN54HC02	12 De	evice and Documentation Support	12
	6.6 Electrical Characteristics5	12	.1 Documentation Support	12
	6.7 Switching Characteristics 6	12	2.2 Related Links	12
	6.8 Operating Characteristics 6	12	.3 Community Resources	1
	6.9 Typical Characteristics	12	.4 Trademarks	12
7	Parameter Measurement Information	12	2.5 Electrostatic Discharge Caution	12
8	Detailed Description 8	12	.6 Glossary	12
Ū	8.1 Overview		echanical, Packaging, and Orderable formation	1:

## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

#### Changes from Revision E (August 2003) to Revision F

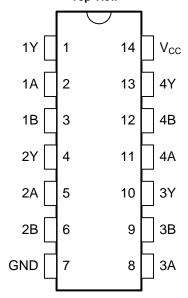
Page

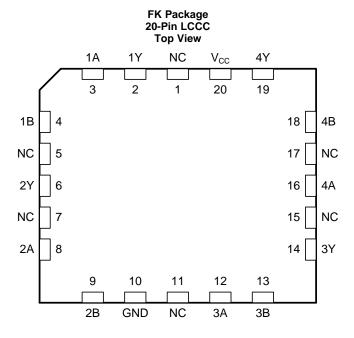
- Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.



# 5 Pin Configuration and Functions

D, DB, N, NS, PW, J, or W Package 14-Pin SOIC, SSOP, PDIP, SO, TSSOP, CDIP, or CFP Top View





#### **Pin Functions**

	PIN			
NAME	SOIC, SSOP, PDIP, SO, TSSOP, CDIP, CFP	LCCC	I/O	DESCRIPTION
1Y	1	2	0	Gate 1 output
1A	2	3	1	Gate 1 input A
1B	3	4	1	Gate 1 input B
2Y	4	6	0	Gate 2 output
2A	5	8	1	Gate 2 input A
2B	6	9	1	Gate 2 input B
GND	7	10	_	Ground Pin
3A	8	12	1	Gate 3 input A
3B	9	13	1	Gate 3 input B
3Y	10	14	0	Gate 3 output
4A	11	16	1	Gate 4 input A
4B	12	18	1	Gate 4 input B
4Y	13	19	0	Gate 4 output
V <sub>CC</sub>	14	20	_	Power pin
NC	_	1, 5, 7, 11, 15, 17	_	No internal connection

Copyright © 1982–2015, Texas Instruments Incorporated



## 6 Specifications

#### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		-0.5	7	V
I <sub>IK</sub>	Input clamp current <sup>(2)</sup>	$V_I < 0$ or $V_I > V_{CC}$		±20	mA
I <sub>OK</sub>	Output clamp current <sup>(2)</sup>	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	$V_O = 0$ to $V_{CC}$		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
Tj	T <sub>j</sub> Operating virtual junction temperature			150	°C
T <sub>stg</sub>	Storage temperature		-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### 6.2 ESD Ratings - SN74HC02

			VALUE	UNIT
V	Floatrootatio dia sharas	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±1500	V
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±2000	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

#### 6.3 Recommended Operating Conditions

See (1).

			MIN	NOM	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5	6	V
		V <sub>CC</sub> = 2 V	1.5			
$V_{IH}$	High-level input voltage	V <sub>CC</sub> = 4.5 V	3.15			V
	$V_{CC} = 6 V$	4.2				
		V <sub>CC</sub> = 2 V			0.5	
V <sub>IL</sub> Low-level input voltage	V <sub>CC</sub> = 4.5 V			1.35	V	
		V <sub>CC</sub> = 6 V			1.8	
VI	Input voltage		0		V <sub>CC</sub>	V
Vo	Output voltage		0		V <sub>CC</sub>	V
		V <sub>CC</sub> = 2 V			1000	
Δt/Δν	Input transition rise and fall time	$V_{CC} = 4.5 \text{ V}$			500	ns/V
		$V_{CC} = 6 V$			400	
_	Operating free air temperature	SN54HC02	-55		125	۰.
T <sub>A</sub> Operating free-air temperature		SN74HC02	-40		85	°C

All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. See the TI application report, Implications of Slow or Floating CMOS Inputs, SCBA004.

Product Folder Links: SN54HC02 SN74HC02

<sup>2)</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



#### 6.4 Thermal Information - SN74HC02

			SN74HC02				
THERMAL METRIC(1)		D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance <sup>(1)</sup>	94	105.4	54.9	88.8	119.6	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	53.2	57.3	42.5	46.5	48.4	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	48.7	52.7	34.7	47.6	61.3	°C/W
ΨЈТ	Junction-to-top characterization parameter	15.6	22.6	27.9	16.8	5.6	°C/W
ΨЈВ	Junction-to-board characterization parameter	48.4	52.2	34.6	47.2	60.7	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

#### 6.5 Thermal Information – SN54HC02

THERMAL METRIC <sup>(1)</sup>					
		J (CDIP)	W (CFP)	FK (LCCC)	UNIT
		14 PINS	14 PINS	20 PINS	
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	53.8	89.6	61.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	73.1	164.1	59.8	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	26.7	15.5	11.7	°C/W

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

## 6.6 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST C	ONDITIONS	V <sub>cc</sub>	T <sub>A</sub>	MIN	TYP	MAX	UNIT	
			2 V		1.9	1.998			
	I <sub>OH</sub> = -20 μA	4.5 V		4.4	4.499				
			6 V		5.9	5.999			
				T <sub>A</sub> = 25°C	3.98	4.3			
V <sub>OH</sub>	$V_I = V_{IH}$ or $V_{IL}$	$I_{OH} = -4 \text{ mA}$	4.5 V	SN54HC02	3.7			V	
				SN74HC02	3.84				
				T <sub>A</sub> = 25°C	5.48	5.8			
		$I_{OH} = -5.2 \text{ mA}$	6 V	SN54HC02	5.2				
				SN74HC02	5.34				
			2 V			0.002	0.1		
		$I_{OL} = 20 \mu A$	4.5 V			0.001	0.1		
			6 V			0.001	0.1		
				T <sub>A</sub> = 25°C		0.17	0.26		
V <sub>OL</sub>	$V_I = V_{IH}$ or $V_{IL}$	$I_{OL} = 4 \text{ mA}$	4.5 V	SN54HC02			0.4	V	
				SN74HC02			0.33		
					T <sub>A</sub> = 25°C		0.15	0.26	
		$I_{OL} = 5.2 \text{ mA}$	6 V	SN54HC02			0.4		
				SN74HC02			0.33		
				T <sub>A</sub> = 25°C		±0.1	±100		
I	$V_I = V_{CC}$ or 0		6 V	SN54HC02, SN74HC02			±1000	nA	
				T <sub>A</sub> = 25°C			2		
I <sub>CC</sub>	$V_I = V_{CC}$ or 0, $I_O$	= 0	6 V	SN54HC02			40	μΑ	
				SN74HC02			20		
C <sub>i</sub>			2 V to 6 V			3	10	pF	

Product Folder Links: SN54HC02 SN74HC02



#### 6.7 Switching Characteristics

over recommended operating free-air temperature range,  $C_L = 50 \text{ pF}$  (unless otherwise noted) (see Figure 2)

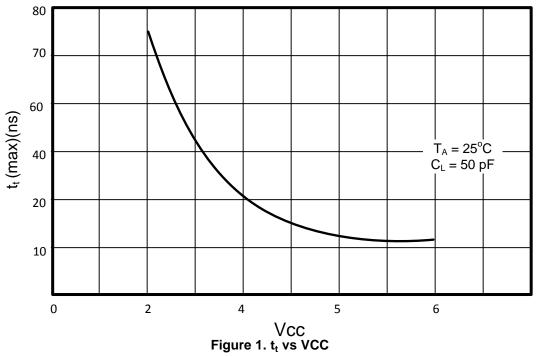
PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub>	T <sub>A</sub>	MIN	TYP	MAX	UNIT	
				T <sub>A</sub> = 25°C		45	90		
			2 V	SN54HC02			135		
				SN74HC02			115		
				T <sub>A</sub> = 25°C		9	18		
t <sub>pd</sub>	A or B	Υ	4.5 V	SN54HC02			27	ns	
				SN74HC02			23		
				T <sub>A</sub> = 25°C		8	15		
			6 V	SN54HC02			23		
			SN74	SN74HC02			20		
				$T_A = 25^{\circ}C$		38	75		
			2 V	SN54HC02			110		
				SN74HC02			95		
				$T_A = 25^{\circ}C$		8	15		
t <sub>t</sub>	A or B	Υ	4.5 V	SN54HC02			22	ns	
					SN74HC02			19	
				$T_A = 25^{\circ}C$		6	13		
			6 V	SN54HC02			19		
				SN74HC02			16		

## 6.8 Operating Characteristics

 $T_A = 25^{\circ}C$ 

PARAMETER		TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub>	Power dissipation capacitance per gate	No load	22	pF

# 6.9 Typical Characteristics

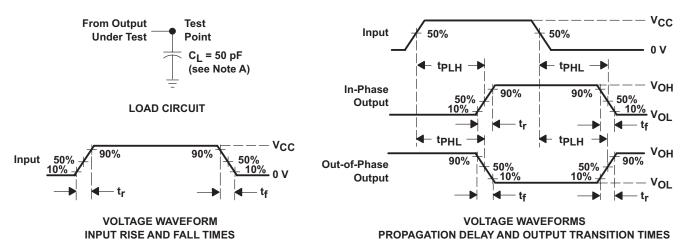


Submit Documentation Feedback

Copyright © 1982–2015, Texas Instruments Incorporated



#### 7 Parameter Measurement Information



- A. C<sub>L</sub> includes probe and test-fixture capacitance.
- B. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz,  $Z_O = 50 \Omega$ ,  $t_f = 6$  ns,  $t_f = 6$  ns.
- C. The outputs are measured one at a time with one input transition per measurement.
- D. t<sub>PLH</sub> and t<sub>PHL</sub> are the same as t<sub>pd</sub>.

Figure 2. Load Circuit and Voltage Waveforms

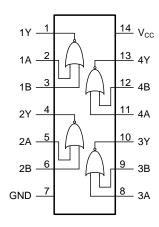


## 8 Detailed Description

#### 8.1 Overview

The SNx4HC02 devices are quad 2-input NOR gates. These devices are members of the High-Speed CMOS (HC) logic family. The HC family of logic is optimized to operate with a 5-V supply, is low noise without characteristic overshoot and undershoot, has low power consumption, small propagation delay, balanced propagation delay and transition times, and operates over a wide temperature range.

#### 8.2 Functional Block Diagram



Copyright © 2016, Texas Instruments Incorporated

#### 8.3 Feature Description

#### 8.3.1 Operating Voltage Range

The SNx4HC series of devices offer a wide operating voltage range from 2 V to 6 V.

#### 8.3.2 LSTTL Loads

The outputs of the SNx4HC series can drive up to 10 LSTTL loads.

#### 8.3.3 Low Power Consumption

The SNx4HC02 offers low power consumption of 20 µA maximum.

#### 8.3.4 Output Drive Capability

At 5 V, the outputs have ±4 mA of output drive capability.

#### 8.3.5 Low Input Current Leakage

Inputs have low input current leakage of 1 µA maximum.

#### 8.4 Device Functional Modes

Table 1 lists the functional modes of the SNx4HC02.

**Table 1. Function Table** 

INP	OUTPUT	
Α	В	Υ
Н	Х	L
X	Н	L
L	L	Н





Figure 3. Logic Diagram (Positive Logic)



## 9 Application and Implementation

#### NOTE

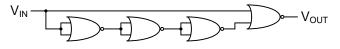
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 9.1 Application Information

The SNX4HC02 is a low-drive CMOS device that can be used for a multitude of NOR type functions. The device can produce 4 mA of drive current at 5 V, making it Ideal for driving multiple outputs and good for low-noise applications. This application is for using a single SNX4HC02 as a falling edge detector circuit.

The edge detector operates by using the inherent propagation delay from input to output of each device stage. In steady-state, the inputs to the output stage will always be different, and thus the output will always be low. Only during the brief time when both inputs are low (that is, immediately following a falling edge on  $V_{IN}$ ), the output will be high.

### 9.2 Typical Application



Copyright © 2016, Texas Instruments Incorporated

Figure 4. Falling Edge Detector Schematic

#### 9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive also creates fast edges into light loads, so routing and load conditions must be considered to prevent ringing.

The output pulse time will be approximately three times  $t_{pd}$  from *Switching Characteristics* for the selected  $V_{CC}$ , device, and temperature range.

#### 9.2.2 Detailed Design Procedure

- Recommended Input Conditions For rise time and fall time specifications, see Δt/ΔV in Recommended
   Operating Conditions.
  - For specified high and low levels, see V<sub>IH</sub> and V<sub>IL</sub> in Recommended Operating Conditions.
  - Inputs are not overvoltage tolerant, allowing them to go as high as V<sub>CC</sub>.
- 2. Recommend Output Conditions
  - Load currents must not exceed 20 mA per output and 50 mA total for the part.
  - Outputs must not be pulled above V<sub>CC</sub>.



## **Typical Application (continued)**

#### 9.2.3 Application Curve

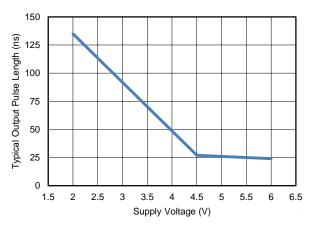


Figure 5. Typical Output Pulse Length Over V<sub>CC</sub> Range

## 10 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in *Recommended Operating Conditions*. Each  $V_{CC}$  pin must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends a 0.1- $\mu$ F bypass capacitor. If there are multiple  $V_{CC}$  pins, TI recommends a 0.01- $\mu$ F or 0.022- $\mu$ F bypass capacitors for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. Two bypass capacitors of value 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. For best results, install the bypass capacitor(s) as close to the power pin as possible.

## 11 Layout

#### 11.1 Layout Guidelines

When using multiple bit logic devices, inputs must not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input AND gate are used, or when only 3 of the 4-buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in *Absolute Maximum Ratings* are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ , whichever makes more sense or is more convenient. It is acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the I/Os so they also cannot float when disabled.

## 11.2 Layout Example

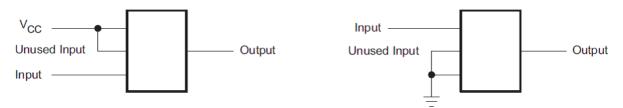


Figure 6. Layout Recommendation



## 12 Device and Documentation Support

#### 12.1 Documentation Support

#### 12.1.1 Related Documentation

For related documentation, see the following:

Implications of Slow or Floating CMOS Inputs, SCBA004

#### 12.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 2. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54HC02	Click here	Click here	Click here	Click here	Click here
SN74HC02	Click here	Click here	Click here	Click here	Click here

### 12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

#### 12.4 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

#### 12.5 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

## 13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.





17-Mar-2017

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package Drawing	Pins 14	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)
5962-8404101VCA	ACTIVE	CDIP	J		1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-8404101VC A SNV54HC02J
84041012A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	OST-PLATE N / A for Pkg Type -55 to 125		84041012A SNJ54HC 02FK
8404101CA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8404101CA SNJ54HC02J
8404101DA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8404101DA SNJ54HC02W
IM38510/65101B2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	JM38510/ 65101B2A
M38510/65101BCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type -55 to 125		JM38510/ 65101BCA
M38510/65101BDA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 65101BDA
M38510/65101B2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	JM38510/ 65101B2A
M38510/65101BCA	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 65101BCA
M38510/65101BDA	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	JM38510/ 65101BDA
SN54HC02J	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	SN54HC02J
SN74HC02D	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02
SN74HC02DBR	ACTIVE	SSOP	DB	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02
SN74HC02DE4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02
SN74HC02DG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02
SN74HC02DR	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 85	HC02





17-Mar-2017

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	
SN74HC02DRE4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM -40 to 8		HC02	
SN74HC02DRG4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02DT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02DTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02N	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU   CU SN	N / A for Pkg Type	-40 to 85	SN74HC02N	
SN74HC02NE4	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-40 to 85	SN74HC02N	
SN74HC02NSR	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02NSRG4	ACTIVE	SO	NS	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02PW	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02PWG4	ACTIVE	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02PWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU   CU SN	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02PWRG4	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SN74HC02PWT	ACTIVE	TSSOP	PW	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HC02	
SNJ54HC02FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	84041012A SNJ54HC 02FK	
SNJ54HC02J	ACTIVE	CDIP	J	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8404101CA SNJ54HC02J	
SNJ54HC02W	ACTIVE	CFP	W	14	1	TBD	A42	N / A for Pkg Type	-55 to 125	8404101DA SNJ54HC02W	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

## **PACKAGE OPTION ADDENDUM**



17-Mar-2017

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54HC02, SN54HC02-SP, SN74HC02:

Catalog: SN74HC02, SN54HC02

Automotive: SN74HC02-Q1, SN74HC02-Q1

Enhanced Product: SN74HC02-EP, SN74HC02-EP



## **PACKAGE OPTION ADDENDUM**

17-Mar-2017

• Military: SN54HC02

• Space: SN54HC02-SP

#### NOTE: Qualified Version Definitions:

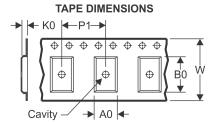
- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications
- Space Radiation tolerant, ceramic packaging and qualified for use in Space-based application

PACKAGE MATERIALS INFORMATION

www.ti.com 10-Mar-2016

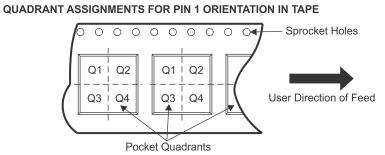
## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

— Reel Width (WT)



#### \*All dimensions are nominal

*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HC02DBR	SSOP	DB	14	2000	330.0	16.4	8.2	6.6	2.5	12.0	16.0	Q1
SN74HC02DR	SOIC	D	14	2500	330.0	16.8	6.5	9.5	2.3	8.0	16.0	Q1
SN74HC02DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC02DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC02DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC02DRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC02DT	SOIC	D	14	250	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HC02PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC02PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC02PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HC02PWT	TSSOP	PW	14	250	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

**PACKAGE MATERIALS INFORMATION** 

www.ti.com 10-Mar-2016



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HC02DBR	SSOP	DB	14	2000	367.0	367.0	38.0
SN74HC02DR	SOIC	D	14	2500	364.0	364.0	27.0
SN74HC02DR	SOIC	D	14	2500	333.2	345.9	28.6
SN74HC02DR	SOIC	D	14	2500	367.0	367.0	38.0
SN74HC02DRG4	SOIC	D	14	2500	367.0	367.0	38.0
SN74HC02DRG4	SOIC	D	14	2500	333.2	345.9	28.6
SN74HC02DT	SOIC	D	14	250	367.0	367.0	38.0
SN74HC02PWR	TSSOP	PW	14	2000	364.0	364.0	27.0
SN74HC02PWR	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74HC02PWRG4	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74HC02PWT	TSSOP	PW	14	250	367.0	367.0	35.0

# FK (S-CQCC-N\*\*)

## LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



## **MECHANICAL DATA**

# NS (R-PDSO-G\*\*)

# 14-PINS SHOWN

#### PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



# W (R-GDFP-F14)

## CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
   Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
   Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



## DB (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE

#### **28 PINS SHOWN**



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

#### IMPORTANT NOTICE

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (http://www.ti.com/sc/docs/stdterms.htm) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.